RENESAS

ISL59448

500MHz Triple 2:1 Gain-of-2, Multiplexing Amplifier

The ISL59448 is a triple channel 2:1 multiplexer featuring integrated buffers with a fixed gain of 2, high slew-rate and excellent bandwidth for video switching. The device features a three-state output (HIZ), which allows the outputs of multiple devices to be tied together. A power-down mode (ENABLE) is included to turn off un-needed circuitry in power sensitive applications. When the ENABLE pin is pulled high, the part enters a power-down mode and consumes just 14mW. An additional feature is a latch enable function ($\overline{\text{LE}}$) that allows independent logic control using a common logic bus.

Ordering Information

PART NUMBER	PACKAGE	TAPE & REEL	PKG. DWG. #
ISL59448IAZ (See Note)	24 Ld QSOP (Pb-free)	-	MDP0040
ISL59448IAZ-T7 (See Note)	24 Ld QSOP (Pb-free)	7"	MDP0040

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

NOT RECOMMENDED FOR NEW DESIGNS NO RECOMMENDED REPLACEMENT contact our Technical Support Center at 1-888-INTERSIL or www.intersil.com/tsc

FN6160 Rev 2.00 March 29, 2006

DATASHEET

Features

- 500MHz bandwidth
- ±1600 V/µs slew rate
- · High impedance buffered inputs
- · Internally set gain-of-2
- High speed three-state outputs (HIZ)
- Power-down mode (ENABLE)
- Latch enable
- ±5V operation
- Supply current 11mA/ch
- · Pb-free plus anneal available (RoHS compliant)

Applications

- · HDTV/DTV analog inputs
- Video projectors
- Computer monitors
- · Set-top boxes
- Security video

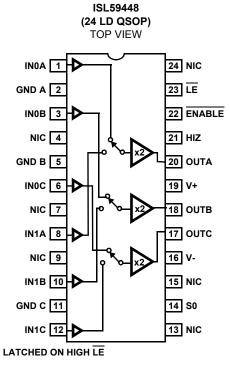
RENESAS

· Broadcast video equipment

TABLE 1. CHANNEL SELECT LOGIC TABLE ISL59448

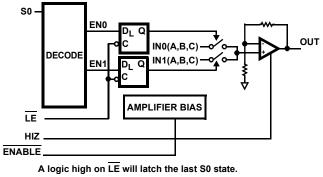
S0	ENABLE	HIZ	LE	OUTPUT
0	0	0	0	INO (A, B, C)
1	0	0	0	IN1 (A, B, C)
Х	1	Х	Х	Power-down
Х	0	1	Х	High Z
Х	0	0	1	Last S0 State Preserved





NIC = NO INTERNAL CONNECTION

Functional Diagram (each channel)



A logic high on $\overline{\text{LE}}$ will latch the last S0 state. Th<u>is logic</u> state is preserved when cycling HIZ or ENABLE functions.

Absolute Maximum Ratings (T_A = 25°C)

Supply Voltage (V+ to V-)
Input Voltage
Supply Turn-on Slew Rate 1V/µs
Digital & Analog Input Current (Note 1) 50mA
Output Current (Continuous) 50mA
ESD Rating
Human Body Model (Per MIL-STD-883 Method 3015.7) 2500V
Machine Model

Storage Temperature Range	65°C to +150°C
Ambient Operating Temperature	40°C to +85°C
Operating Junction Temperature	40°C to +125°C
Power Dissipation	See Curves

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. If an input signal is applied before the supplies are powered up, the input current must be limited to these maximum values.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

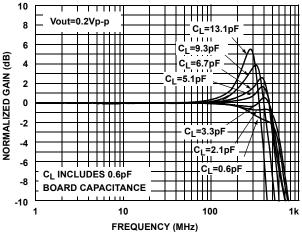
Electrical Specifications V+ = +5V, V- = -5V, GND = 0V, $T_A = 25^{\circ}C$, Vout = $\pm 2V_{P-P} \& R_L = 500\Omega$ to GND, $C_L = 0pF$, unless otherwise specified.

specified.						
PARAMETER	DESCRIPTION CONDITIONS		MIN	TYP	MAX	UNIT
GENERAL						1
+I _S Enabled	Enabled Supply Current	No load, V _{IN} = 0V, Enable Low	27	31	35	mA
-I _S Enabled	Enabled Supply Current	No load, V _{IN} = 0V, Enable Low	-32	-29	-25	mA
+I _S Disabled	Disabled Supply Current	No load, V _{IN} = 0V, Enable High	2.3	2.7	3.3	mA
-I _S Disabled	Disabled Supply Current	No load, V _{IN} = 0V, Enable High	-0.1		0.1	mA
V _{OUT}	Positive and Negative Output Swing	$V_{IN} = \pm 2.5 V; R_{L} = 500 \Omega$	±3.1	±3.9		V
IOUT	Output Current	V _{IN} = 0.825V R _L = 10Ω	±80		±180	mA
V _{OS}	Output Offset Voltage		-40	-25	-10	mV
lb	Input Bias Current	V _{IN} = 0V	-3	-2	-1	μA
R _{OUT}	HIZ Output Resistance	HIZ = Logic High	700	900	1150	Ω
R _{OUT}	Enabled Output Resistance	HIZ = Logic Low		0.2		Ω
R _{IN}	Input Resistance	ut Resistance V _{IN} = ±1.75V 10		10		MΩ
$\rm A_{CL}$ or $\rm A_{V}$	Voltage Gain	R _L = 500Ω	1.94	1.98	2.035	V/V
LOGIC						1
VIH	Input High Voltage (Logic Inputs)			2		V
V _{IL}	Input Low Voltage (Logic Inputs)			0.8		V
IIH	Input High Current (Logic Inputs)	Input High Current (Logic Inputs) $V_{H} = 5V$ 200 258		319	μA	
IIL	Input Low Current (Logic Inputs)	V _L = 0V	-3		3	μA
AC GENERAL						1
PSRR	Power Supply Rejection Ratio DC, PSRR V+ & V- combined 52 72 V _{OUT} = 0dBm 52 72			dB		
Xtalk	Channel to Channel Crosstalk	f = 10MHz, ChX-Ch Y-Talk V_{IN} = 1Vp-p; C _L = 1.1pF	88			dB
Off - ISO	Off-state Isolation	f = 10MHz, Ch-Ch Off Isolation V_{IN} = 1Vp-p; C _L = 1.1pF	72			dB
dG	Differential Gain Error	NTC-7, R _L = 150, C _L = 1.1pF		0.015		%
dP	Differential Phase Error	NTC-7, R _I = 150, C _I = 1.1pF		0.015		0

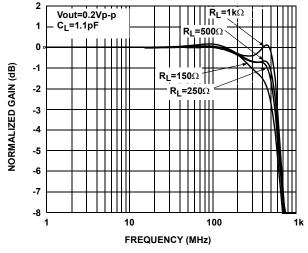


Electrical Specifications V + = +5V, V - = -5V, GND = 0V, $T_A = 25^{\circ}C$, $Vout = \pm 2V_{P-P} \& R_L = 500\Omega$ to GND, $C_L = 0pF$, unless otherwise specified. **(Continued)**

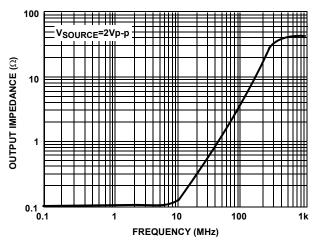
PARAMETER DESCRIPTION CONDITIONS MIN TYP MAX							
	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT	
BW	Small Signal -3dB Bandwidth	V _{OUT} = 0.2Vp-p; R _L = 500Ω, C _L = 1.1pF		570		MHz	
	Large Signal -3dB Bandwidth	V _{OUT} = 2Vp-p; R _L = 500Ω, C _L = 1.1pF		280		MHz	
	Small Signal -3dB Bandwidth	V_{OUT} = 0.2Vp-p; R _L = 150 Ω , C _L = 1.1pF		510		MHz	
	Large Signal -3dB Bandwidth	V_{OUT} = 2Vp-p; R _L = 150Ω, C _L = 1.1pF		260		MHz	
FBW	0.1dB Bandwidth	V_{OUT} = 2Vp-p; R_L = 500 Ω , C_L = 1.1pF		140		MHz	
	0.1dB Bandwidth	V_{OUT} = 2Vp-p; R _L = 150 Ω , C _L = 1.1pF		60		MHz	
SR	Slew Rate	25% to 75%, R _L = 150Ω, Input Enabled, C _L = 1.1pF	1600			V/µs	
FRANSIENT RE	SPONSE				I		
tr, tf Large	Large Signal Rise, Fall TImes, tr, tf, 10% - 90%	V _{OUT} = 2Vp-p; R _L = 500Ω, C _L = 1.1pF		1.2		ns	
Signal		V _{OUT} = 2Vp-p; R _L = 150Ω, C _L = 1.1pF		1.3		ns	
tr, tf, Small	Small Signal Rise, Fall TImes, tr, tf, 10% - 90%	V _{OUT} = 0.2Vp-p; R _L = 500Ω, C _L = 1.1pF		0.7		ns	
Signal		V _{OUT} = 0.2Vp-p; R _L = 150Ω, C _L = 1.1pF		0.85		ns	
ts 0.1%	Settling TIme 0.1%	V _{OUT} = 2Vp-p; R _L = 500Ω, C _L = 1.1pF		5		ns	
		V _{OUT} = 2Vp-p; R _L = 150Ω, C _L = 1.1pF		4.5		ns	
ts 1%	Settling TIme 1%	V _{OUT} = 2Vp-p; R _L = 500Ω, C _L = 1.1pF		2		ns	
		V _{OUT} = 2Vp-p; R _L = 150Ω, C _L = 1.1pF		2.5		ns	
SWITCHING CH	IARACTERISTICS					1	
V _{GLITCH}	Channel -to-Channel Switching Glitch	V _{IN} = 0V, C _L = 1.1pF		40		mV _{P-P}	
	Enable Switching Glitch	V _{IN} = 0V C _L = 1.1pF		250		mV _{P-P}	
	HIZ Switching Glitch	V _{IN} = 0V C _L = 1.1pF		200		mV _{P-P}	
t _{SW-L-H}	Channel Switching Time Low to High	1.2V logic threshold to 10% movement of analog output		18		ns	
t _{SW-H-L}	Channel Switching Time High to Low	1.2V logic threshold to 10% movement of analog output	F 20			ns	
tpd	Propagation Delay	10% to 10%		0.9		ns	
tLH	Latch Enable Hold time	<u>LE</u> = 0		10		ns	













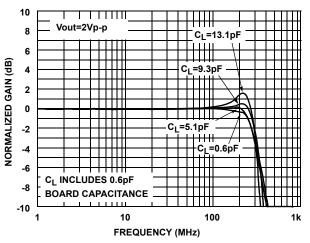
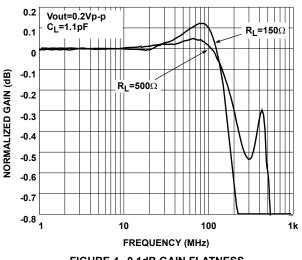
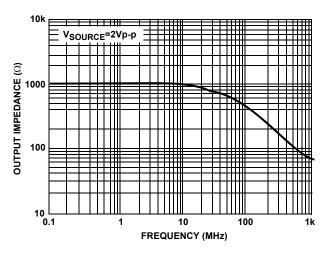


FIGURE 2. LARGE SIGNAL GAIN vs FREQUENCY vs C $_{\rm L}$ INTO 500 Ω LOAD

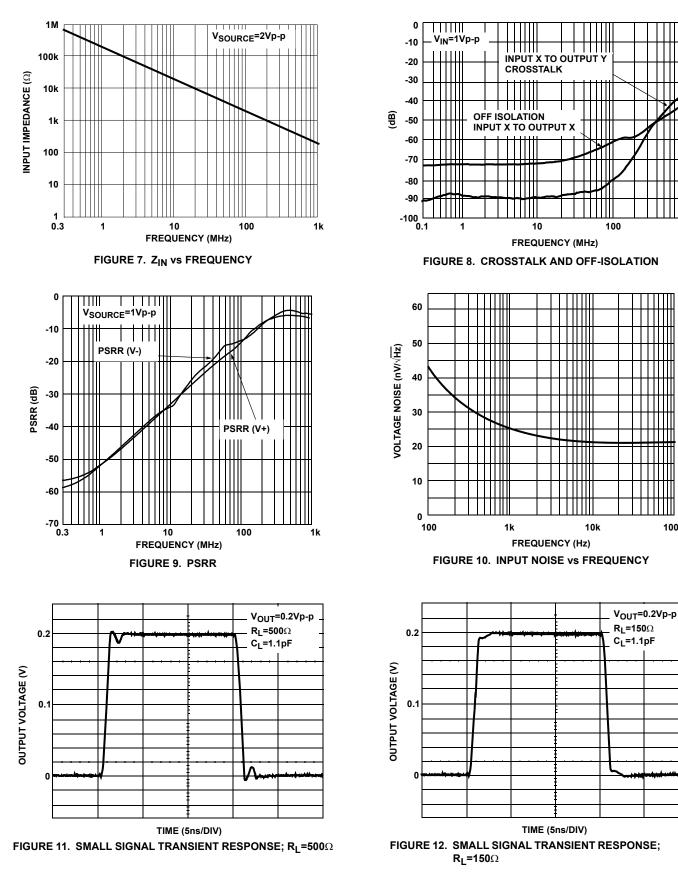








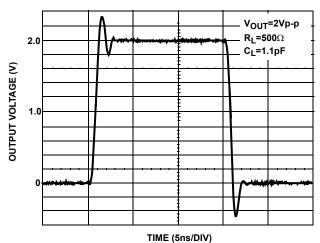






1k

100k





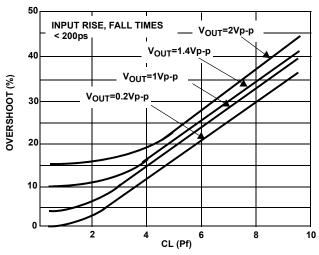
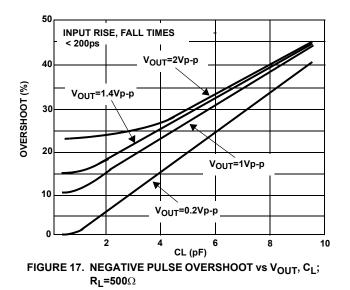
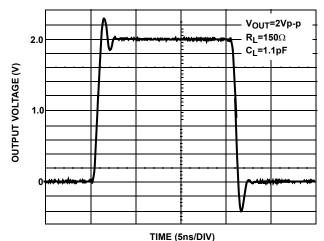
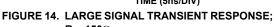


FIGURE 15. POSITIVE PULSE OVERSHOOT vs V_{OUT}, C_L; R_L=500 Ω







R_L=150Ω

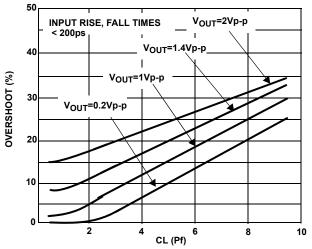
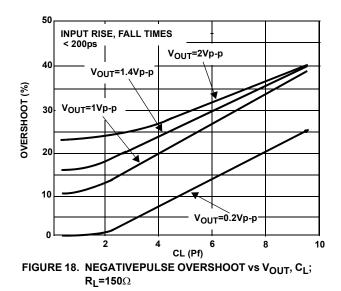
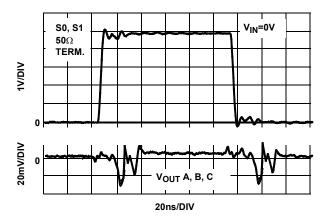
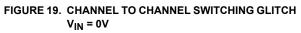


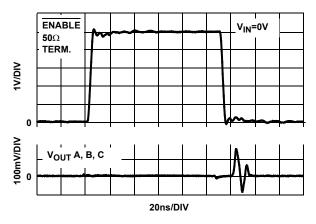
FIGURE 16. POSITIVE PULSE OVERSHOOT vs V_{OUT}, C_L; R_L=150 Ω



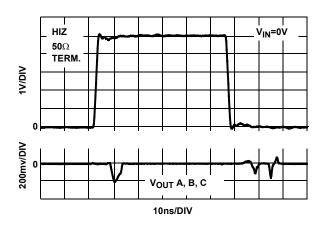




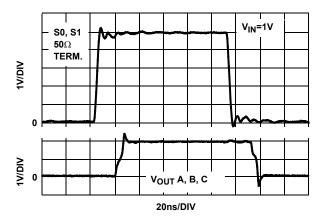




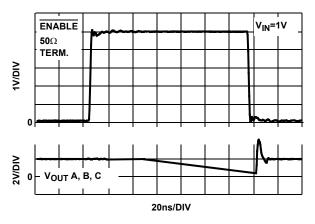




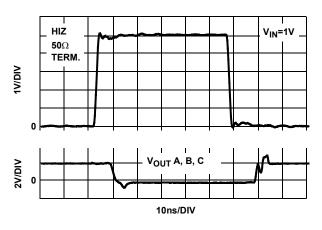














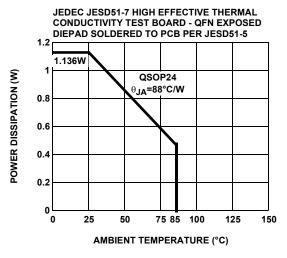
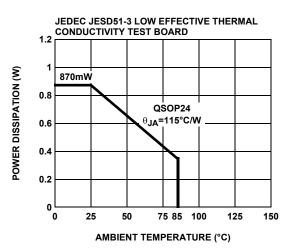


FIGURE 25. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

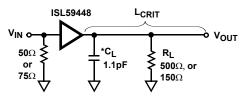




Pin Descriptions

ISL59448 (24 LD QSOP)	PIN NAME	EQUIVALENT CIRCUIT	DESCRIPTION
8	IN1A	Circuit 1	Channel 1 input for output amplifier "A"
4, 7, 9, 13, 15, 24	NIC		Not Internally Connected; it is recommended these pins be tied to ground to minimize crosstalk.
10	IN1B	Circuit 1	Channel 1 input for output amplifier "B"
12	IN1C	Circuit 1	Channel 1 input for output amplifier "C"
5	GNDB	Circuit 4	Ground pin for output amplifier "B"
11	GNDC	Circuit 4	Ground pin for output amplifier "C"
14	S0	Circuit 2	Channel selection pin. LSB (binary logic code)
17	OUTC	Circuit 3	Output of amplifier "C"
18	OUTB	Circuit 3	Output of amplifier "B"
16	V-	Circuit 4	Negative power supply
20	OUTA	Circuit 3	Output of amplifier "A"
19	V+	Circuit 4	Positive power supply
22	ENABLE	Circuit 2	Device enable (active low) w/Internal pull-down resistor. A logic High puts device into power-down mode with the only logic circuitry active. All logic states are preserved post power-down. This state is not recommended for logic control where more than one MUX-amp share the same video output line.
23	LE	Circuit 2	Device latch enable on the ISL59424. A logic high on $\overline{\text{LE}}$ will latch the last (S0, S1) logic state. HIZ and ENABLE functions are not latched with the LE pin.
21	HIZ	Circuit 2	Output disable (active high) w/internal pull-down resistor. A logic high, puts the outputs in a high impedance state. Use this state to control logic when more than one MUX-amp share the same video output line.
6	IN0C	Circuit 1	Channel 0 for output amplifier "C"
3	IN0B	Circuit 1	Channel 0 for output amplifier "B"
1	IN0A	Circuit 1	Channel 0 for output amplifier "A"
2	GNDA	Circuit 4	Ground pin for output amplifier "A"

AC Test Circuits



*CL Includes PCB trace capacitance



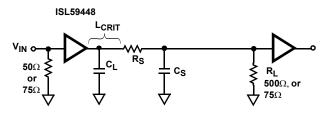
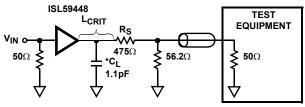
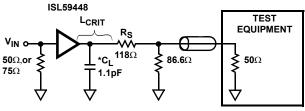


FIGURE 27B. INTER-STAGE APPLICATION CIRCUIT



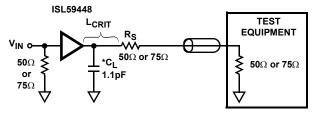
*CL Includes PCB trace capacitance

FIGURE 27C. 500 Ω TEST CIRCUIT WITH 50 Ω LOAD



*CL Includes PCB trace capacitance

FIGURE 27D. 150Ω TEST CIRCUIT WITH 50Ω LOAD



*CL Includes PCB trace capacitance

FIGURE 27E. BACKLOADED TEST CIRCUIT FOR 75 Ω VIDEO CABLE APPLICATION

AC Test Circuits

Figure 27C and 27D illustrate the optimum output load for testing AC performance at 500Ω and 150Ω loads. Figure 27E illustrates the optimun output load for 50Ω and 75Ω cable-driving.

Application Information

General

Key features of the ISL59448 include a fixed gain of 2, buffered high impedance analog inputs and excellent AC performance at output loads down to 150Ω for video cable-driving. The current feedback output amplifiers are stable operating into capacitive loads.

For the best isolation and crosstalk rejection, all GND pins and NIC pins must connect to the GND plane.

AC Design Considerations

High speed current-feed amplifiers are sensitive to capacitance at the inverting input and output terminals. The ISL59448 has an internally set gain of 2, so the inverting input is not accessible. Capacitance at the output terminal increases gain peaking (Figure 1) and pulse overshoot (Figures15 thru 18). The AC response of the ISL59448 is optimized for a total capacitance of 1.1pF over the load range of 150 Ω to 500 Ω .

PC board trace length should be kept to a minimum in order to minimize output capacitance and prevent the need for controlled impedance lines. At 500MHz trace lengths approaching 1" begin exhibiting transmission line behavior and may cause excessive ringing if controlled impedance traces are not used. Figure 27A shows the optimum inter-stage circuit when the total output trace length is less than the critical length of the highest signal frequency.

For applications where pulse response is critical and where inter-stage distances exceed L_{CRIT} , the circuit shown in Figure 27B is recommended. Resistor R_S constrains the capacitance seen by the amplifier output to the trace capacitance from the output pin to the resistor. Therefore, R_S should be placed as close to the ISL59448 output pin as possible. For inter-stage distances much greater than L_{CRIT} , the back-loaded circuit shown in Figure 27E should be used with controlled impedance PCB lines, with R_S and R_L equal to the controlled impedance.

For applications where inter-stage distances are long, but pulse response is not critical, capacitor C_S can be added to low values of R_S to form a low-pass filter to dampen pulse overshoot. This approach avoids the need for the large gain correction required by the -6dB attenuation of the back-loaded controlled impedance interconnect. Load resistor RL is still required but can be 500Ω or greater, resulting in a much smaller attenuation factor.

Control Signals

S0, S1, $\overline{\text{ENABLE}}$, $\overline{\text{LE}}$, HIZ - These are binary coded, TTL/CMOS compatible control inputs. The S0, S1 pins select the inputs. All three amplifiers are switched simultaneously from their respective inputs. The $\overline{\text{ENABLE}}$, $\overline{\text{LE}}$, HIZ pins are used to disable the part to save power, latch in the last logic state and three-state the output amplifiers, respectively. For control signal



rise and fall times less than 10ns the use of termination resistors close to the part will minimize transients coupled to the output.

Power-up Considerations

The ESD protection circuits use internal diodes from all pins the V+ and V- supplies. In addition, a dV/dT- triggered clamp is connected between the V+ and V- pins, as shown in the Equivalent Circuits 1 through 4 section of the Pin Description table. The dV/dT triggered clamp imposes a maximum supply turn-on slew rate of $1V/\mu$ s. Damaging currents can flow for power supply rates-of-rise in excess of $1V/\mu$ s, such as during hot plugging. Under these conditions, additional methods should be employed to ensure the rate of rise is not exceeded.

Consideration must be given to the order in which power is applied to the V+ and V- pins, as well as analog and logic input pins. Schottky diodes (Motorola MBR0550T or equivalent) connected from V+ to ground and V- to ground (Figure 4) will shunt damaging currents away from the internal V+ and V-ESD diodes in the event that the V+ supply is applied to the device before the V- supply.

If positive voltages are applied to the logic or analog video input pins before V+ is applied, current will flow through the internal ESD diodes to the V+ pin. The presence of large decoupling capacitors and the loading effect of other circuits connected to V+, can result in damaging currents through the ESD diodes and other active circuits within the device. Therefore, adequate current limiting on the digital and analog inputs is needed to prevent damage during the time the voltages on these inputs are more positive than V+.

HIZ State

An internal pull-down resistor ensures the device will be active with no connection to the HIZ pin. The HIZ state is established within approximately 15ns (Figure 14) by placing a logic high (>2V) on the HIZ pin. If the HIZ state is selected, the output impedance is ~1000 Ω (Figure 6). The supply current during this state is same as the active state.

ENABLE and Power-down States

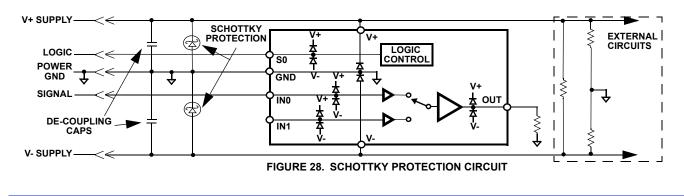
The enable pin is active low. An internal pull-down resistor ensures the device will be active with no connection to the ENABLE pin. The Power-down state is established within approximately 200ns (Figure 22), if a logic high (>2V) is placed on the ENABLE pin. In the power-down state, the output has no leakage but has a large variable capacitance (on the order of 15pF), and is capable of being back-driven. Under this condition, large incoming slew rates can cause fault currents of tens of mA. Therefore, the parallel connection of multiple outputs is not recommended unless the application can tolerate the limited powerdown output impedance.

LE State

The ISL59448 is equipped with a Latch Enable pin. A logic high (>2V) on the \overline{LE} pin latches the last logic state. This logic state is preserved when cycling HIZ or ENABLE functions.

Limiting the Output Current

No output short circuit current limit exists on these parts. All applications need to limit the output current to less than 50mA. Adequate thermal heat sinking of the parts is also required.



FN6160 Rev 2.00 March 29, 2006



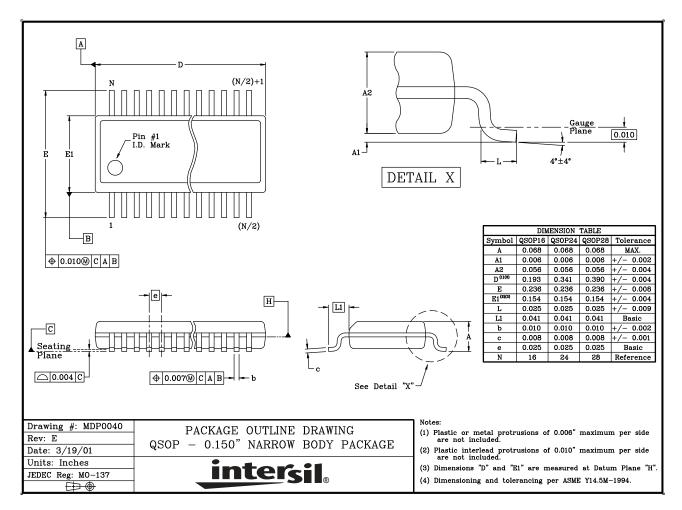
PC Board Layout

The AC performance of this circuit depends greatly on the care taken in designing the PC board. The following are recommendations to achieve optimum high frequency performance from your PC board.

- The use of low inductance components such as chip resistors and chip capacitors is strongly recommended.
- Minimize signal trace lengths. Trace inductance and capacitance can easily limit circuit performance. Avoid sharp corners, use rounded corners when possible. Vias in the signal lines add inductance at high frequency and should be avoided. PCB traces greater than 1" begin to exhibit transmission line characteristics with signal rise/fall times of 1ns or less. High frequency performance may be degraded for traces greater than one inch, unless strip line are used.
- Match channel-channel analog I/O trace lengths and layout symmetry. This will minimize propagation delay mismatches.
- Maximize use of AC de-coupled PCB layers. All signal I/O lines should be routed over continuous ground planes (i.e. no split planes or PCB gaps under these lines). Avoid vias in the signal I/O lines.
- Use proper value and location of termination resistors. Termination resistors should be as close to the device as possible.
- When testing use good quality connectors and cables, matching cable types and keeping cable lengths to a minimum.
- Minimum of 2 power supply de-coupling capacitors are recommended (1000pF, 0.01μ F) as close to the devices as possible Avoid vias between the cap and the device because vias add unwanted inductance. Larger caps can be farther away. When vias are required in a layout, they should be routed as far away from the device as possible.
- The NIC pins are placed on both sides of the input pins. These pins are not internally connected to the die. It is recommended these pins be tied to ground to minimize crosstalk.



QSOP Package Outline Drawing



NOTE: The package drawing shown here may not be the latest version. To check the latest revision, please refer to the Intersil website at <<u>http://www.intersil.com/design/packages/index.asp></u>

© Copyright Intersil Americas LLC 2005-2006. All Rights Reserved. All trademarks and registered trademarks are the property of their respective owners.

For additional products, see www.intersil.com/en/products.html

Intersil products are manufactured, assembled and tested utilizing ISO9001 quality systems as noted in the quality certifications found at www.intersil.com/en/support/qualandreliability.html

Intersil products are sold by description only. Intersil may modify the circuit design and/or specifications of products at any time without notice, provided that such modification does not, in Intersil's sole judgment, affect the form, fit or function of the product. Accordingly, the reader is cautioned to verify that datasheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see www.intersil.com

